

Form PTO-1449 (MODIFIED)	U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE	ATTY. DOCKET NO. 040301/0578	SERIAL NO. Unassigned
INFORMATION DISCLOSURE CITATION <i>(Use several sheets if necessary)</i>		APPLICANT Nobutoshi AOKI et al.	
		FILING DATE November 16, 1999	GROUP ART UNIT Unassigned

U.S. PATENT DOCUMENTS

EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB- CLASS	FILING DATE IF APPROPRIATE
J	A1	5,356,821	10/1994	Naruse et al.	437	34	

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FOREIGN PATENT DOCUMENTS

	REF	DOCUMENT NUMBER	DATE	COUNTRY	CLASS	SUB- CLASS	TRANSLATION	
							YES	NO
J	A2	2876866	01/1999	Japan				Abstract
	A3	4-25176	01/1992	Japan				Abstract

OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

EXAMINER INITIAL	REF	DOCUMENT NUMBER	DATE	NAME	CLASS	SUB- CLASS	FILING DATE IF APPROPRIATE
J	A4	Tsu-Jae King et al., IEEE ELECTRON DEVICE LETTERS vol 12, no. 10, "A Variable-Work-Function Polycrystalline-Si _{1-x} Ge _x Gate Material for Submicrometer CMOS Technologies, pp. 533-535, (10/10/91)					

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